

**Comparative characteristics of diffusion-welded high-voltage stacks and connected in series Schottky diodes**

**Sleptšuk, Natalja; Korolkov, Oleg; Land, Raul; Toompuu, Jana; Annus, Paul; Rang, Toomas** BEC 2016 : 2016 15th Biennial Baltic Electronics Conference : proceedings of the 15th Biennial Baltic Electronics Conference : Tallinn University of Technology, October 3-5, 2016, Tallinn, Estonia 2016 / p. 39-42 : ill [http://www.ester.ee/record=b2150914\\*est](http://www.ester.ee/record=b2150914*est)

**High-voltage diffusionwelded stacks on the basis of SiC Schottky diodes**

**Korolkov, Oleg; Sleptšuk, Natalja; Annus, Paul; Land, Raul; Rang, Toomas** Silicon carbide and related materials 2015 (ICSRM 2015) : selected, peer reviewed papers from the 16th International Conference on Silicon Carbide and Related Materials, October 4-9, 2015, Giardini Naxos, Italy 2016 / p. 790-794 : ill <http://dx.doi.org/10.4028/www.scientific.net/MSF.858.790>

**SIC schottky diode rectifier bridge represented as the diffusion-welded stack**

**Korolkov, Oleg; Kozlovski, Vitali V.; Lebedev, Alexander A.; Land, Raul; Sleptšuk, Natalja; Toompuu, Jana; Rang, Toomas** Silicon Carbide and Related Materials 2016 : selected, peer reviewed papers from the 11th European Conference on Silicon Carbide and Related Materials 2016 (ECSCRM 2016), September 25-29, 2016, Halkidiki, Greece 2017 / p. 697-700 : ill <https://doi.org/10.4028/www.scientific.net/MSF.897.697>